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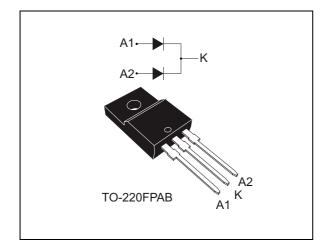




## FERD40U50C

## Field effect rectifier

#### Datasheet - production data



### Features

- ST advanced rectifier process
- Stable leakage current over reverse voltage
- Reduced leakage current
- Low forward voltage drop
- High frequency operation
- Insulated package: TO-220FPAB
  - Insulating voltage: 2000 V<sub>RMS</sub> sine

### Description

This dual rectifier is based on a proprietary technology that achieved the best in class  $V_{\text{F}}/I_{\text{R}}$  for a given silicon surface.

Packaged in TO-220FPAB, this device is intended to be used in rectification and freewheeling operations in switch-mode power supplies.

Symbol	Value
I <sub>F(AV)</sub>	2 x 20 A
V <sub>RRM</sub>	50 V
T <sub>j</sub> (max)	+175 °C
V <sub>F</sub> (typ)	0.43 V

This is information on a product in full production.

## 1 Characteristics

#### Table 2. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit			
V <sub>RRM</sub>	Repetitive peak reverse voltage			50	V	
I <sub>F(RMS)</sub>	Forward rms current	Forward rms current			Α	
	Average forward current, $\delta = 0.5$	T <sub>c</sub> = 120 °C	Per diode	20	А	
<sup>I</sup> F(AV)	Average forward current, $\delta = 0.5$ $T_c = 90 \text{ °C}$ Per device		Per device	40		
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			250	Α	
T <sub>stg</sub>	Storage temperature range			-65 to + 175	°C	
T <sub>j</sub> <sup>(1)</sup>	Maximum operating junction temperature			175	°C	
dDtot				•		

1.  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink.

#### Table 3. Thermal resistance

Symbol	Parameter	Value (max)	Unit	
D	Junction to case	Per diode	4.1	
R <sub>th(j-c)</sub>		Total	3.3	°C/W
R <sub>th(c)</sub>	Coupling	2.4		

When diodes 1 and 2 are used simultaneously:

 $T_{j(diode1)} = P_{(diode1)} \times R_{th(j-c)}(per diode) + P_{(diode2)} \times R_{th(c)}$ 

#### Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	Reverse leakage current	T <sub>j</sub> = 25 °C	$V_{R} = V_{RRM}$			0.8	mA
I <sub>B</sub> <sup>(1)</sup>		T <sub>j</sub> = 125 °C			30	60	mA
IR' /		T <sub>j</sub> = 25 °C	V _ 25 V			460	μA
		T <sub>j</sub> = 125 °C	V <sub>R</sub> = 35 V		20	40	mA
	Forward voltage drop	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 5 A		0.25		
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 10 A		0.33		
V <sub>F</sub> <sup>(2)</sup>		T <sub>j</sub> = 25 °C	l <sub>F</sub> = 15 A		0.41	0.46	V
v <sub>F</sub> (-,		T <sub>j</sub> = 125 °C			0.39	0.43	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 20 A		0.44	0.49	
		T <sub>j</sub> = 125 °C			0.43	0.48	

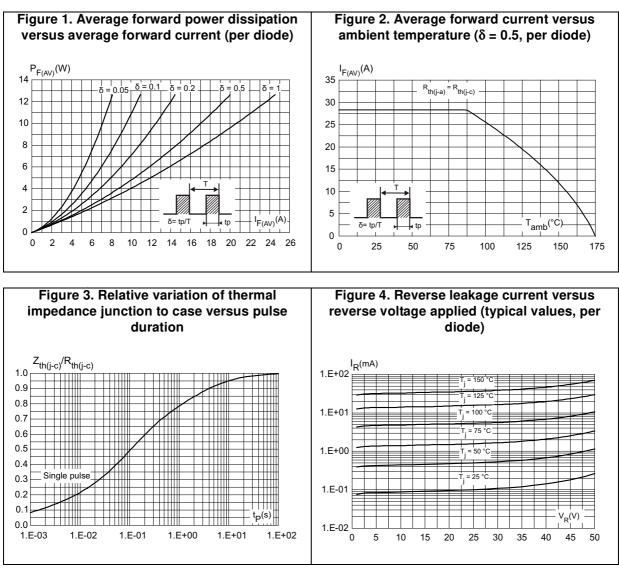
1. Pulse test:  $t_p = 5 \text{ ms}, \delta < 2\%$ 

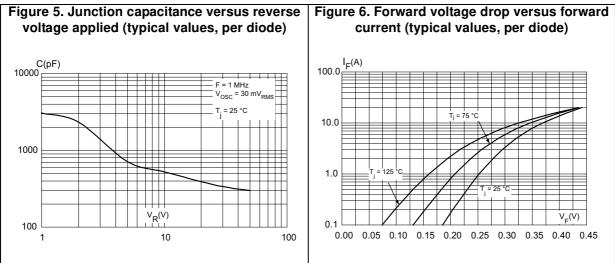
2. Pulse test:  $t_p = 380 \ \mu s, \ \delta < 2\%$ 

To evaluate the conduction losses use the following equation:

 $P = 0.329 \text{ x } I_{F(AV)} + 0.007 I_{F}^{2}_{(RMS)}$ 









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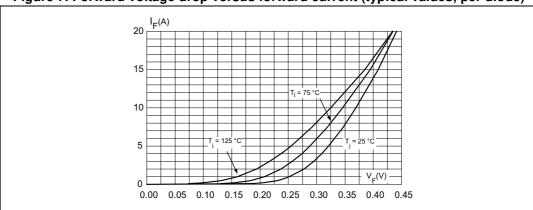


Figure 7. Forward voltage drop versus forward current (typical values, per diode)



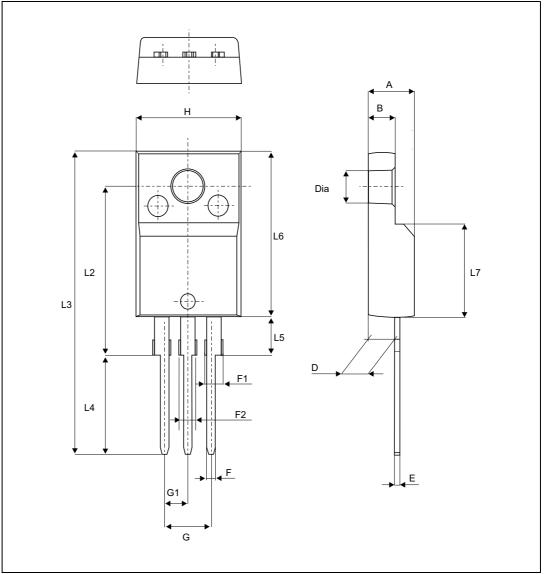
## 2 Package information

- Epoxy meets UL94, V0
- Recommended torque value for TO-220FPAB: 0.55 N.m
- Maximum torque value for TO-220FPAB: 0.7 N.m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

## 2.1 TO-220FPAB package information







Dimensions						
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.4		4.6	0.173		0.181
В	2.5		2.7	0.098		0.106
D	2.5		2.75	0.098		0.108
Е	0.45		0.70	0.018		0.027
F	0.75		1	0.030		0.039
F1	1.15		1.70	0.045		0.067
F2	1.15		1.70	0.045		0.067
G	4.95		5.20	0.195		0.205
G1	2.4		2.7	0.094		0.106
Н	10		10.4	0.393		0.409
L2		16 Тур.			0.63 Typ.	
L3	28.6		30.6	1.126		1.205
L4	9.8		10.6	0.386		0.417
L5	2.9		3.6	0.114		0.142
L6	15.9		16.4	0.626		0.646
L7	9.00		9.30	0.354		0.366
Dia.	3.00		3.20	0.118		0.126

Table 5. T0-220FPAB package mechanical data



## **3** Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
FERD40U50CFP	FERD40U50CFP	TO-220FPAB	1.9 g	50	Tube

## 4 Revision history

Date	Revision	Changes
17-Jun-2015	1	Initial release.



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